








	<h2>SI7452DP-T1-E3</h2>
	<p>Hersteller-Teilenummer: SI7452DP-T1-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 60V 11.5A PPAK SO-8</p> <p>Datenblätter:  SI7452DP-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 502 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI7452DP-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 60V 11.5A PPAK SO-8
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	502 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	PowerPAK® SO-8
Supplier Device-Gehäuse	PowerPAK® SO-8
Verlustleistung (max)	1.9W (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	60V
Strom - Ununterbrochener Abfluss (Id) bei 25 °C	11.5A (Ta)
Rds On (Max) @ Id, Vgs	8.3 mOhm @ 19.3A, 10V
VGS (th) (Max) @ Id	4.5V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	160nC @ 10V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)



















































SI7452DP-T1-E3 ist neu im Original, Suche SI7452DP-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI7452DP-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen. Anfrage SI7452DP-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI7452DP-T1-GE3 Vishay / Siliconix MOSFET N-CH 60V 11.5A PPAK SO-8</p>	 <p>SI7454CDP-T1-GE3 Vishay / Siliconix MOSFET N-CH 100V 22A PPAK SO-8</p>	 <p>SI7451DP-T1 Vishay Precision Group SI7451DP-T1 VISHAY</p>	 <p>SI7454DDP-T1-E3 VISHAY VISHAY PAKSO-8</p>
 <p>SI7454CDP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 100V 22A PPAK SO-8</p>	 <p>SI7450DP. VIS SI7450DP. VIS</p>	 <p>SI7450DP-T1-RE3 Electro-Films (EFI) / Vishay N-CHANNEL 200-V (D-S) MOSFET</p>	 <p>SI7452DP-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 60V 11.5A PPAK SO-8</p>

heiße Teile

Mehr

 SI7446BDP-T1-E3	 SI7446BDP-T1-GE3	 SI7446BDP-T1-GE3	 SI7446BDP-T1-T3	 SI7446DP
 SI7446DP-T1	 SI7446DP-T1-GE3	 SI7446DP-T1.	 SI7447ADP	 SI7447ADP-T1-E3
 SI7447ADP-T1-E3	 SI7447ADP-T1-GE3	 SI7447ADP-T1-GE3	 SI7447DP-T1-GE3	 SI7448DP
 SI7448DP-T1-E3	 SI7448DP-T1-E3	 SI7448DP-T1-GE3	 SI7448DP-T1-GE3	 SI7450DP
 SI7450DP-T1-E3	 SI7450DP-T1-E3	 SI7450DP-T1-GE3	 SI7450DP-T1-GE3	 SI7452DP-T1-E3
 SI7452DP-T1-GE3	 SI7452DP-T1-GE3	 SI7454CDP-T1-GE3	 SI7454CDP-T1-GE3	 SI7454DDP-T1-GE3
 SI7454DDP-T1-GE3	 SI7454DP	 SI7454DP-T1-E3	 SI7454DP-T1-E3	 SI7454DP-T1-GE3
 SI7454DP-T1-GE3	 SI7456CDP-T1-GE3	 SI7456CDP-T1-GE3	 SI7456DDP-T1-GE3	 SI7456DDP-T1-GE3
 SI7456DP	 SI7456DP-T1-E3	 SI7456DP-T1-E3	 SI7456DP-T1-GE3	 SI7456DP-T1-GE3
 SI7458DP-T1-E3	 SI7459DP-T1-E3	 SI7459DP-T1-E3	 SI7459DP-T1-GE3	 SI7459DP-T1-GE3

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